

UTC UNISONIC TECHNOLOGIES CO., LTD

MGBR10L150C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

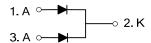
DESCRIPTION

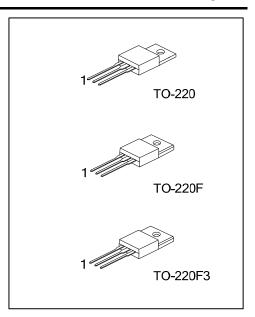
The UTC MGBR10L150C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

- * Low forward voltage drop
- * High switching speed



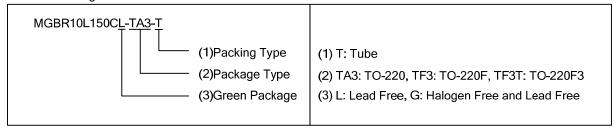




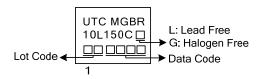
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	Facking	
MGBR10L150CL-TA3-T	MGBR10L150CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR10L150CL-TF3-T	MGBR10L150CG-TF3-T	TO-220F	Α	K	Α	Tube	
MGBR10L150CL-TF3T-T	MGBR10L150CG-TF3T-T	TO-220F3	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



MARKING



www.unisonic.com.tw 1 of 3

■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	150	V
Working Peak Reverse Voltage		V_{RWM}	150	V
Peak Repetitive Reverse Voltage		V_{RRM}	150	V
Average Rectified Output Current Per	Per Leg		5	Α
Device	Total	I _O	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	100	Α
Operating Junction Temperature		TJ	-65~+150	°C
Storage Temperature		T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient		θ_{JA}	62.5	°C/W	
Junction to Case	TO-220	0	2	°C/M	
	TO-220F/TO-220F3	θ _{JC}	3.31	°C/W	

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	150			V
Forward Voltage Drop	VEM	I _F =5A, T _J =25°C			0.90	V
		I _F =5A, T _J =125°C			0.75	V
Leakage Current (Note 1)	I _{PM}	V _R =150V, T _J =25°C			100	μA
		V _R =150V, T _{.I} =125°C			15	mΑ

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.